

TLP559(IGM)

TRANSISTOR INVERTER

INVERTER FOR AIR CONDITIONER

LINE RECEIVER

IPM INTERFACES

The TOSHIBA TLP559(IGM) consists of a GaAlAs high-output light emitting diode and a high speed detector of one chip photo diode-transistor.

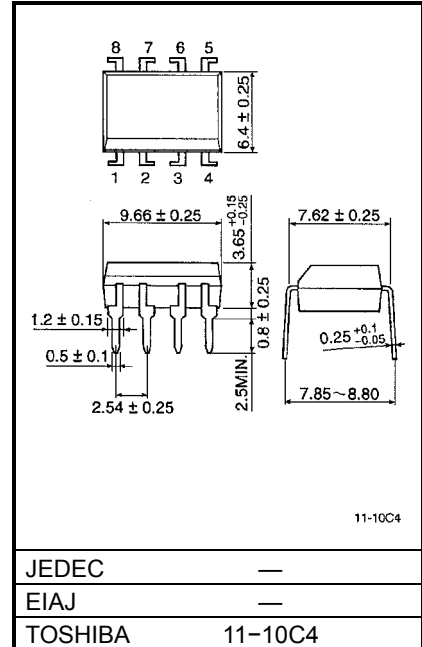
This unit is 8-lead DIP package.

TLP559(IGM) has no internal base connection, and a Faraday shield integrated on the photodetector chip provides an effective common mode noise transient immunity.

TLP559(IGM) guarantees minimum and maximum of propagation delay time, switching time dispersion, and high common mode transient immunity. There for TLP559(IGM) is suitable for isolation interface between IPM(Intelligent Power Module) and control IC circuits in motor control application.

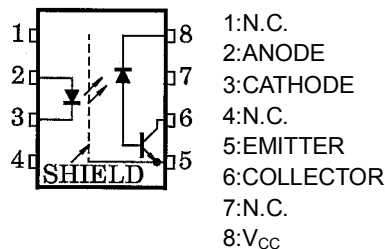
- Isolation Voltage : 2500 Vrms (Min)
- Common Mode Transient Immunity : $\pm 10 \text{ kV}/\mu\text{s}$ (Min)
@ $V_{CM} = 1500 \text{ V}$
- Switching Time : $t_{pHL}, t_{pLH} = 0.1 \mu\text{s}$ (Min)
= $0.8 \mu\text{s}$ (Max)
@ $I_F = 10 \text{ mA}$, $V_{CC} = 15 \text{ V}$, $R_L = 20 \text{ k}\Omega$, $T_a = 25^\circ\text{C}$
- Switching Time Dispersion : $0.7 \mu\text{s}$ (Max)
($|t_{pLH} - t_{pHL}|$)
- TTL Compatible
- UL Recognized : UL1577, File No. E67349

Unit: mm

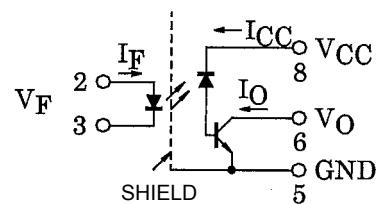


Weight: 0.54 g

PIN CONFIGURATION(Top view)



SCHEMATIC



MAXIMUM RATINGS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	RATING	UNIT
LED	Forward Current (Note 1)	I_F	25	mA
	Pulse Forward Current (Note 2)	I_{FP}	50	mA
	Peak Transient Forward Current (Note 3)	I_{FPT}	1	A
	Reverse Voltage	V_R	5	V
	Diode Power Dissipation (Note 4)	P_D	45	mW
DETECTOR	Output Current	I_O	8	mA
	Peak Output Current	I_{OP}	16	mA
	Output Voltage	V_O	-0.5~20	V
	Supply Voltage	V_{CC}	-0.5~30	V
	Output Power Dissipation (Note 5)	P_O	100	mW
Operating Temperature Range		T_{opr}	-55~100	°C
Storage Temperature Range		T_{stg}	-55~125	°C
Lead Solder Temperature(10s) (Note 6)		T_{sol}	260	°C
Isolation Voltage(AC, 1min., R.H.≤60%, Ta=25°C) (Note 7)		BV_S	2500	Vrms

(Note 1) Derate 0.5mA above 70°C.

(Note 2) 50% duty cycle, 1ms pulse width.

Derate -1.0mA/°C above 70°C.

(Note 3) Pulse width $PW \leq 1\mu s$, 300pps.

(Note 4) Derate 0.9mW/°C above 70°C.

(Note 5) Derate 2mW/°C above 70°C.

(Note 6) Soldering portion of lead : up to 2mm from the body of the device.

(Note 7) Device considered a two terminal device : pins 1,2,3 and 4 shorted together and pins 5,6,7 and 8 shorted together.

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC		SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
LED	Forward Voltage	V_F	$I_F = 16 \text{ mA}$	—	1.65	1.85	V
	Forward Voltage Temperature Coefficient	$\Delta V_F / \Delta T_a$	$I_F = 16 \text{ mA}$	—	-2	—	mV / °C
	Reverse Current	I_R	$V_R = 5 \text{ V}$	—	—	10	μA
	Capacitance between Terminal	CT	$V = 0, f = 1 \text{ MHz}$	—	45	—	pF
DETECTOR	High Level Output Current	$I_{OH(1)}$	$I_F = 0 \text{ mA}, V_{CC} = V_O = 5.5 \text{ V}$	—	3	500	nA
		$I_{OH(2)}$	$I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}$ $V_O = 20 \text{ V}$	—	—	5	μA
		I_{OH}	$I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}$ $V_O = 20 \text{ V}, T_a = 70^\circ\text{C}$	—	—	50	
	High Level Supply Voltage	I_{CCH}	$I_F = 0 \text{ mA}, V_{CC} = 30 \text{ V}$	—	0.01	1	μA
	Supply Voltage	V_{CC}	$I_{CC} = 0.01 \text{ mA}$	30	—	—	V
	Output Voltage	V_O	$I_O = 0.5 \text{ mA}$	20	—	—	V

COUPLED ELECTRICAL CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Current Transfer Ratio	I_O / I_F	$I_F = 10 \text{ mA}, V_{CC} = 4.5 \text{ V}$ $V_O = 0.4 \text{ V}$	25	35	75	%
		$I_F = 10 \text{ mA}, V_{CC} = 4.5 \text{ V}$ $V_O = 0.4 \text{ V}, T_a = -25 \sim 100^\circ\text{C}$	15	—	—	
Low Level Output Voltage	V_{OL}	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$ $I_O = 2.4 \text{ mA}$	—	—	0.4	V

ISOLATION CHARACTERISTICS (Ta = 25°C)

CHARACTERISTIC	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Capacitance Input to Output	CS	$V = 0, f = 1 \text{ MHz}$	—	0.8	—	pF
Isolation Resistance	R_S	$R.H. \leq 60\%, V_S = 500 \text{ V}$	5×10^{10}	10^{14}	—	Ω
Isolation Voltage	BV_S	AC, 1minute	2500	—	—	Vrms
		AC, 1second, in oil	—	5000	—	
		DC, 1minute, in oil	—	5000	—	Vdc

SWITCHING CHARACTERISTICS (Ta = 25°C, V_{CC} = 15 V)

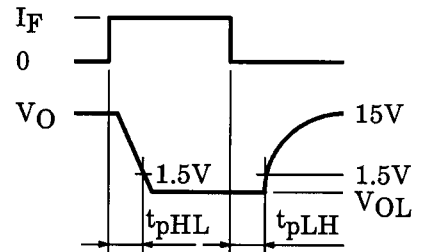
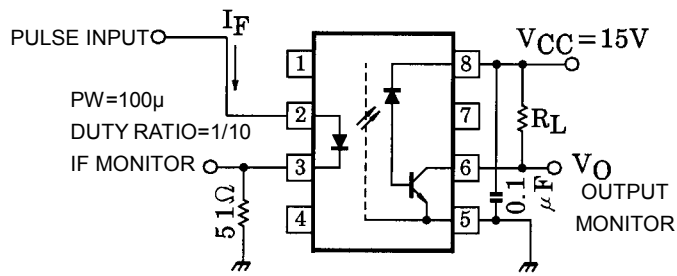
CHARACTERISTIC	SYMBOL	TEST CIRCUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Propagation Delay Time (H→L)	t_{pHL} t_{pLH}	1	$I_F = 10 \text{ mA}, R_L = 20 \text{ k}\Omega$	0.1	0.45	0.8	μs
Propagation Delay Time (L→H)			$I_F = 10 \text{ mA}, R_L = 20 \text{ k}\Omega$ $T_a = 0\sim 85^\circ\text{C}$	0.1	0.45	0.9	
			$I_F = 10 \text{ mA}, R_L = 20 \text{ k}\Omega$ $T_a = -25\sim 100^\circ\text{C}$	0.1	0.45	1.0	
Switching Time Dispersion between ON and OFF	$ t_{pLH}-t_{pHL} $		$I_F = 10 \text{ mA}, R_L = 20 \text{ k}\Omega$	—	0.15	0.7	μs
			$I_F = 10 \text{ mA}, R_L = 20 \text{ k}\Omega$ $T_a = 0\sim 85^\circ\text{C}$	—	0.25	0.8	
			$I_F = 20 \text{ mA}, R_L = 20 \text{ k}\Omega$ $T_a = -25\sim 100^\circ\text{C}$	—	0.25	0.9	
Common Mode Transient Immunity at Logic High Output (Note 8)	CM_H	2	$I_F = 0 \text{ mA},$ $V_{CM} = 1500 \text{ V}_{p-p},$ $R_L = 20 \text{ k}\Omega$	10000	15000	—	$\text{V} / \mu\text{s}$
Common Mode Transient Immunity at Logic Low Output (Note 8)	CM_L		$I_F = 10 \text{ mA},$ $V_{CM} = 1500 \text{ V}_{p-p},$ $R_l = 20 \text{ k}\Omega$	-10000	-15000	—	$\text{V} / \mu\text{s}$

(Note 8) CM_L is the maximum rate of fall of the common mode voltage that can be sustained with the output voltage in the logic low state ($V_O < 1\text{V}$).

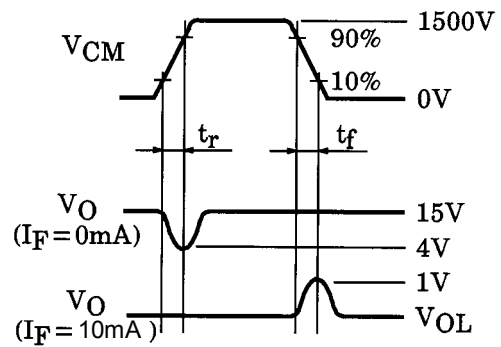
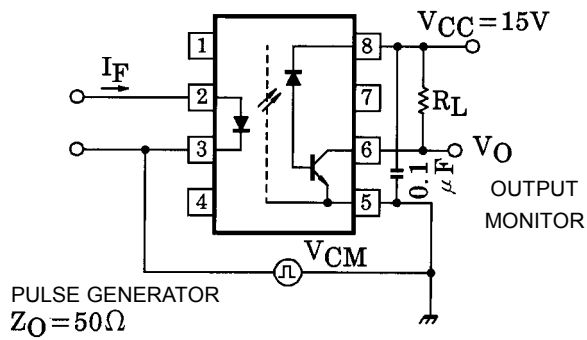
CM_H is the maximum rate of rise of the common mode voltage that can be sustained with the output voltage in the logic high state ($V_O > 4\text{V}$).

(Note 9) Maximum electrostatic discharge voltage for any pins : 100V (C=200pF, R=0)

TEST CIRCUIT 1 : Switching time test circuit



TEST CIRCUIT 2 : Common mode noise immunity test circuit



$$CM_H = \frac{1200(V)}{t_r(\mu s)}, \quad CM_L = \frac{1200(V)}{t_f(\mu s)}$$

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